NSN 5962-01-447-5769

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View Online at https://aerobasegroup.com/nsn/5962-01-447-5769 **Body Length:** 1.060 inches **Body Width:** 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and electrostatic sensitive and monolithic and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 16 input **Current Rating Per Characteristic:** 70.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** Power up sequencer Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 20.00 nanoseconds acc/pac detector tint control **Memory Device Type:** Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:**

N/a

Unit Of Measure:

20 printed circuit Shelf Life:

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Demilitarization:

Yes - demil/mli

Fiig:

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